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## NPN Triple Diffused Planar Silicon Transistor

Absolute Maximum Ratings $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ unless otherwise noted

| Symbol | Parameter | Value | Units |
| :--- | :--- | :---: | :---: |
| $\mathrm{V}_{\mathrm{CBO}}$ | Collector-Base Voltage | 1200 | V |
| $\mathrm{~V}_{\mathrm{CEO}}$ | Collector-Emitter Voltage | 600 | V |
| $\mathrm{~V}_{\mathrm{EBO}}$ | Emitter-Base Voltage | 12 | V |
| $\mathrm{I}_{\mathrm{C}}$ | Collector Current (DC) | 4 | A |
| $\mathrm{I}_{\mathrm{CP}}$ | ${ }^{*}$ Collector Current (Pulse) | 8 | A |
| $\mathrm{I}_{\mathrm{B}}$ | Base Current (DC) | 2 | A |
| $\mathrm{I}_{\mathrm{BP}}$ | ${ }^{*}$ Base Current (Pulse) | 4 | A |
| $\mathrm{P}_{\mathrm{C}}$ | Collector Dissipation $\left(\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}\right)$ | 75 | W |
| $\mathrm{~T}_{\mathrm{J}}$ | Junction Temperature | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{STG}}$ | Storage Temperature | $-65 \sim 150$ | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{E}_{\mathrm{AS}}$ | Avalanche Energy $\left(\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}\right)$ | 3 | mJ |
| ${ }^{\text {Pulse Test }: \text { Pulse Width }=5 \text { ms, Duty Cycle } \leq 10 \%}$ |  |  |  |

Thermal Characteristics $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ unless otherwise noted

| Symbol | Characteristics |  | Rating | Unit |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{R}_{\text {өjc }}$ | Thermal Resistance | Junction to Case | 1.65 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{R}_{\text {өja }}$ |  | Junction to Ambient | 62.5 |  |
| $\mathrm{T}_{\mathrm{L}}$ | Maximun Lead Temperature for Soldering Purpose : 1/8" from Case for 5 seconds |  | 270 | ${ }^{\circ} \mathrm{C}$ |

Electrical Characteristics $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ unless otherwise noted

| Symbol | Parameter | Test Condition |  | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{BV}_{\text {CBO }}$ | Collector-Base Breakdown Voltage | $\mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA}, \mathrm{I}_{\mathrm{E}}=0$ |  | 1200 | 1350 |  | V |
| $\mathrm{BV}_{\text {CEO }}$ | Collector-Emitter Breakdown Voltage | $\mathrm{I}_{\mathrm{C}}=5 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=0$ |  | 600 | 750 |  | V |
| $\mathrm{BV}_{\text {EBO }}$ | Emitter-Base Breakdown Voltage | $\mathrm{I}_{\mathrm{E}}=500 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{C}}=0$ |  | 12 | 13.7 |  | V |
| $\mathrm{I}_{\text {CES }}$ | Collector Cut-off Current | $\begin{aligned} & \mathrm{V}_{\mathrm{CES}}=1200 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{BE}}=0 \end{aligned}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ |  |  | 100 | $\mu \mathrm{A}$ |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ |  |  | 500 |  |
| $I_{\text {CEE }}$ | Collector Cut-off Current | $\mathrm{V}_{\mathrm{CE}}=600 \mathrm{~V}, \mathrm{I}_{\mathrm{B}}=0$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ |  |  | 100 | $\mu \mathrm{A}$ |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ |  |  | 500 |  |
| $\mathrm{I}_{\text {EBO }}$ | Emitter Cut-off Current | $\mathrm{V}_{\mathrm{EB}}=12 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=0$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ |  |  | 10 | $\mu \mathrm{A}$ |
| $\mathrm{h}_{\text {FE }}$ | DC Current Gain | $\mathrm{V}_{\mathrm{CE}}=1 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=0.5 \mathrm{~A}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 15 | 20 | 35 |  |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ | 10 | 13 |  |  |
|  |  | $\mathrm{V}_{\mathrm{CE}}=1 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=2 \mathrm{~A}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 4 | 6 |  |  |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ | 3 | 4.1 |  |  |
|  |  | $\mathrm{V}_{\mathrm{CE}}=2.5 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=1 \mathrm{~A}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 12 | 18 | 30 |  |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ | 8 | 10 |  |  |
| $\mathrm{V}_{\text {CE }}$ (sat) | Collector-Emitter Saturation Voltage | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=0.5 \mathrm{~A}, \\ & \mathrm{I}_{\mathrm{B}}=0.05 \mathrm{~A} \end{aligned}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ |  | 0.28 | 0.6 | V |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ |  | 0.5 | 1.0 | V |
|  |  | $\mathrm{I}_{\mathrm{C}}=1 \mathrm{~A}, \mathrm{I}_{\mathrm{B}}=0.2 \mathrm{~A}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ |  | 0.18 | 0.5 | V |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ |  | 0.3 | 0.75 | V |
|  |  | $\mathrm{I}_{\mathrm{C}}=2 \mathrm{~A}, \mathrm{I}_{\mathrm{B}}=0.4 \mathrm{~A}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ |  | 0.5 | 1.5 | V |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ |  | 2.0 | 3.0 | V |
| $\mathrm{V}_{\mathrm{BE}}$ (sat) | Base-Emitter Saturation Voltage | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=0.8 \mathrm{~A}, \\ & \mathrm{I}_{\mathrm{B}}=0.08 \mathrm{~A} \end{aligned}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ |  | 0.77 | 1.0 | V |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ |  | 0.60 | 0.9 | V |
|  |  | $\mathrm{I}_{\mathrm{C}}=2 \mathrm{~A}, \mathrm{I}_{\mathrm{B}}=0.4 \mathrm{~A}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ |  | 0.85 | 1.2 | V |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ |  | 0.70 | 1.0 | V |
| $\mathrm{C}_{\text {ib }}$ | Input Capacitance | $\mathrm{V}_{\mathrm{EB}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=0, \mathrm{f}=1 \mathrm{MHz}$ |  |  | 600 | 750 | pF |
| $\mathrm{C}_{\mathrm{ob}}$ | Output Capacitance | $\mathrm{V}_{\mathrm{CB}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{E}}=0, \mathrm{f}=1 \mathrm{MHz}$ |  |  | 75 | 100 | pF |
| $\mathrm{f}_{\mathrm{T}}$ | Current Gain Bandwidth Product | $\mathrm{I}_{\mathrm{C}}=0.5 \mathrm{~A}, \mathrm{~V}_{\mathrm{CE}}=10 \mathrm{~V}$ |  |  | 11 |  | MHz |
| $\mathrm{V}_{\mathrm{F}}$ | Diode Forward Voltage | $\mathrm{I}_{\mathrm{F}}=1 \mathrm{~A}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ |  | 0.83 | 1.3 | V |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ |  | 0.7 |  | V |
|  |  | $I_{F}=2 A$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ |  | 0.88 | 1.5 | V |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ |  | 0.8 |  | V |

Electrical Characteristics $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ unless otherwise noted

| Symbol | Parameter | Test Condition |  | Min | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{fr}}$ | Diode Froward Recvery Time (di/dt=10A/ $\mu \mathrm{s}$ ) | $\begin{aligned} & \mathrm{I}_{\mathrm{F}}=0.4 \mathrm{~A} \\ & \mathrm{I}_{\mathrm{F}}=1 \mathrm{~A} \\ & \mathrm{I}_{\mathrm{F}}=2 \mathrm{~A} \end{aligned}$ |  |  | $\begin{aligned} & 770 \\ & 870 \\ & 1.2 \\ & \hline \end{aligned}$ |  | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \\ & \mu \mathrm{~s} \end{aligned}$ |
| $\mathrm{V}_{\text {CE }}$ (DSAT) | Dynamic Saturation Voltage | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=1 \mathrm{~A}, \\ & \mathrm{I}_{\mathrm{B} 1}=100 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{CC}}=300 \mathrm{~V} \end{aligned}$ | @ 1 $\mu \mathrm{s}$ |  | 10 |  | V |
|  |  |  | @ 3 $\mu \mathrm{s}$ |  | 3 |  | V |
|  |  | $\begin{aligned} & \hline \mathrm{I}_{\mathrm{C}}=2 \mathrm{~A}, \\ & \mathrm{I}_{\mathrm{B} 1}=400 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{CC}}=300 \mathrm{~V} \\ & \hline \end{aligned}$ | @ 1 $\mu \mathrm{s}$ |  | 10 |  | V |
|  |  |  | @ 3 $\mu \mathrm{s}$ |  | 2 |  | V |
| RESISTIVE LOAD SWITCHING (D.C $\leq 10 \%$, Pulse Width $=40 \mu \mathrm{~s}$ ) |  |  |  |  |  |  |  |
| $\mathrm{t}_{\mathrm{ON}}$ | Turn ON Time | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=2 \mathrm{~A}, \mathrm{I}_{\mathrm{B}_{1}}=0.4 \mathrm{~A} \\ & \mathrm{I}_{\mathrm{B} 2}=1 \mathrm{~A}, \\ & \mathrm{~V}_{\mathrm{CC}}=300 \mathrm{~V} \\ & \mathrm{R}_{\mathrm{L}}=150 \Omega \end{aligned}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ |  | 160 | 250 | ns |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ |  | 170 |  | ns |
| ${ }_{\text {t }}$ TG | Storage Time |  | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ |  | 1.5 | 2.5 | $\mu \mathrm{s}$ |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ |  | 1.7 |  | $\mu \mathrm{s}$ |
| $\mathrm{t}_{\mathrm{F}}$ | Fall Time |  | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ |  | 125 | 300 | ns |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ |  | 160 |  | ns |
| $\mathrm{t}_{\mathrm{ON}}$ | Turn ON Time | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=2 \mathrm{~A}, \mathrm{I}_{\mathrm{B} 1}=0.4 \mathrm{~A} \\ & \mathrm{I}_{\mathrm{B} 2}=0.4 \mathrm{~A}, \\ & \mathrm{~V}_{\mathrm{CC}}=300 \mathrm{~V} \\ & \mathrm{R}_{\mathrm{L}}=150 \Omega \end{aligned}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ |  | 170 | 300 | ns |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ |  | 175 |  | ns |
| ${ }_{\text {t }}$ STG | Storage Time |  | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ |  | 2.8 | 3.5 | $\mu \mathrm{s}$ |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ |  | 3.1 |  | $\mu \mathrm{s}$ |
| $\mathrm{t}_{\mathrm{F}}$ | Fall Time |  | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ |  | 400 | 650 | ns |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ |  | 850 |  | ns |

INDUCTIVE LOAD SWITCHING (VCC=15V)

| ${ }^{\text {t }}$ STG | Storage Time | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=2 \mathrm{~A}, \mathrm{I}_{\mathrm{B} 1}=0.4 \mathrm{~A} \\ & \mathrm{I}_{\mathrm{B} 2}=1 \mathrm{~A}, \mathrm{~V}_{\mathrm{Z}}=300 \mathrm{~V} \\ & \mathrm{~L}_{\mathrm{C}}=200 \mathrm{H} \end{aligned}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 1.75 | 2.5 | $\mu \mathrm{s}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ | 2.2 |  | $\mu \mathrm{s}$ |
| $\mathrm{t}_{\mathrm{F}}$ | Fall Time |  | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 100 | 250 | ns |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ | 100 |  | ns |
| ${ }_{\text {t }}$ | Cross-over Time |  | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 210 | 400 | ns |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ | 250 |  | ns |
| $\mathrm{t}_{\text {STG }}$ | Storage Time | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=2 \mathrm{~A}, \mathrm{I}_{\mathrm{B} 1}=0.4 \mathrm{~A} \\ & \mathrm{I}_{\mathrm{B} 2}=0.4 \mathrm{~A}, \\ & \mathrm{~V}_{\mathrm{CC}}=300 \mathrm{~V} \\ & \mathrm{~L}_{\mathrm{C}}=200 \mathrm{H} \end{aligned}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 3.6 | 4.5 | $\mu \mathrm{s}$ |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ | 4.2 |  | $\mu \mathrm{s}$ |
| $\mathrm{t}_{\mathrm{F}}$ | Fall Time |  | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 170 | 350 | ns |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ | 320 |  | ns |
| $\mathrm{t}_{\mathrm{C}}$ | Cross-over Time |  | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 540 | 800 | ns |
|  |  |  | $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ | 1.1 |  | ns |

## Typical Characteristics



Figure 1. Static Characteristic


Figure 3. Collector-Emitter Saturation Voltage


Figure 5. Typical Collector Saturation Voltage


Figure 2. DC current Gain


Figure 4. Collector-Emitter Saturation Voltage


Figure 6. Base-Emitter Saturation Voltage

Typical Characteristics (Continued)


Figure 7. Base-Emitter Saturation Voltage


Figure 9. Collector Output Capacitance


Figure 11. Inductive Switching Time, $\mathrm{t}_{\mathrm{fi}}$


Figure 8. Diode Forward Voltage


Figure 10. Inductive Switching Time, $\mathrm{t}_{\mathrm{si}}$


Figure 12. Inductive Switching Time, $\mathrm{t}_{\mathrm{c}}$

Typical Characteristics (Continued)


Figure 13. Inductive Switching Time, $\mathrm{t}_{\mathrm{si}}$


Figure 15. Inductive Switching Time, $\mathrm{t}_{\mathrm{c}}$


Figure 17. Resistive Switching Time, $\mathrm{t}_{\mathrm{si}}$


Figure 14. Inductive Switching Time, $\mathbf{t}_{\mathrm{fi}}$


Figure 16. Resistive Switching Time, $\mathrm{t}_{\mathrm{on}}$


Figure 18. Resistive Switching Time, $\mathrm{t}_{\mathrm{fi}}$

Typical Characteristics (Continued)


Figure 21. Resistive Switching Time, $\mathrm{t}_{\mathrm{fi}}$


Figure 23. Inductive Switching Time, $\mathbf{t}_{\mathrm{fi}}$


Figure 20. Resistive Switching Time, $\mathbf{t}_{\text {si }}$


Figure 22. Inductive Switching Time, $\mathrm{t}_{\mathrm{si}}$


Figure 24. Inductive Switching Time, $\mathbf{t}_{\mathbf{c}}$

Typical Characteristics (Continued)


Figure 25. Forward Bias Safe Operating Area


Figure 26. Power Derating


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